TOSHIBA Field-Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

# SSM3K7002BF

### High-Speed Switching Applications

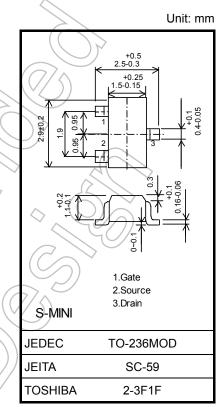
#### Analog Switch Applications

- Small package
- Low ON-resistance :  $R_{DS(ON)} = 3.3 \Omega \text{ (max)} (@V_{GS} = 4.5 \text{ V})$ 
  - :  $R_{DS(ON)} = 2.6 \Omega (max) (@V_{GS} = 5 V)$

:  $R_{DS(ON)} = 2.1 \Omega (max) (@V_{GS} = 10 V)$ 

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	60		
Gate-source voltage		V <sub>GSS</sub>	±20	$(\checkmark \checkmark)$	
Drain current	DC	I <sub>D</sub>	200	MA	
	Pulse	I <sub>DP</sub>	800	NUA	
Drain power dissipation		PD	200	∕ mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 12 mg (typ.)

absolute maximum ratings. Please design the appropriate reliability upon reviewing the

Note: Using continuously under heavy loads (e.g. the application of high

temperature, etc.) may cause this product to decrease in the

temperature/current/voltage and the significant change in

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the

Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Char	acteristics	Symbol	Test Condition		Min	Тур	Max	Unit
Gate leakage curr	eakage current $I_{GSS}$ $V_{GS}$ = ± 20 V, $V_{DS}$ = 0 V			_	_	±10	μA	
Drain-source breakdown voltage		V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V		60	_	_	V
		V (BR) DSX	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = -10 V	45	_	_		
Drain cutoff currer	nt	IDSS	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$		_	_	1	μA
Gate threshold voltage		V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.25 mA		1.5	_	3.1	V
Forward transfer admittance		Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$	(Note 1)	225	_	_	mS
Drain-source ON-resistance		R <sub>DS (ON)</sub>	$I_D = 500 \text{ mA}, V_{GS} = 10 \text{ V}$	(Note 1)	_	1.62	2.1	Ω
			$I_D = 100 \text{ mA}, V_{GS} = 5 \text{ V}$	(Note 1)	_	1.90	2.6	
			$I_D = 100 \text{ mA}, V_{GS} = 4.5 \text{ V}$	(Note 1)	_	2.10	3.3	
Input capacitance		C <sub>iss</sub>	$V_{DS}$ = 25 V, $V_{GS}$ = 0 V, f = 1 MHz		_	17.0	_	pF
Reverse transfer capacitance		C <sub>rss</sub>			_	1.9	_	
Output capacitance		C <sub>oss</sub>			_	3.6	_	
Switching time	Turn-on delay time	td <sub>(on)</sub>			_	3.3	6.6	ns
	Turn-off delay time	td <sub>(off)</sub>			_	14.5	40	
Drain-source forward voltage		V <sub>DSF</sub>	I <sub>D</sub> = -200 mA, V <sub>GS</sub> = 0 V	(Note 1)		-0.84	-1.2	V

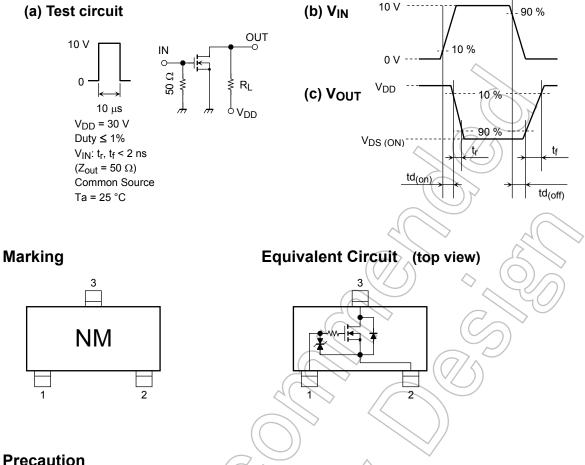
# Electrical Characteristics (Ta = 25°C)

Note1: Pulse test

Start of commercial production 2009-08

# Switching Time Test Circuit

#### (a) Test circuit



#### Precaution

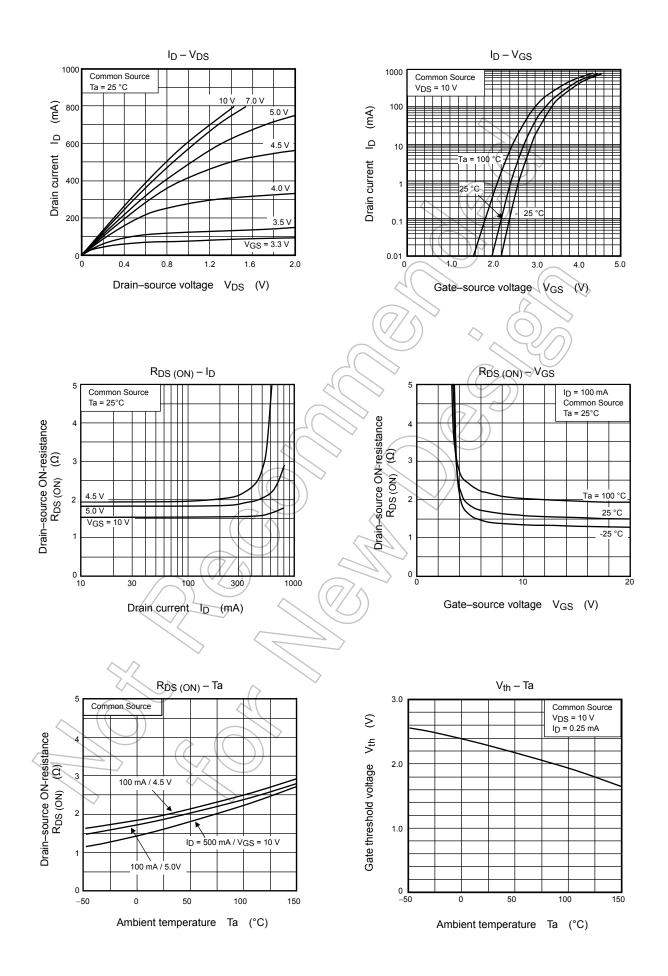
Let Vth be the voltage applied between gate and source that causes the drain current (ID) to be low (0.25 mA for the SSM3K7002BF). Then, for normal switching operation, VGS(on) must be higher than Vth, and VGS(off) must be lower than Vth. This relationship can be expressed as: VGS(off) < Vth < VGS(on). Take this into consideration when using the device.

# Handling Precaution

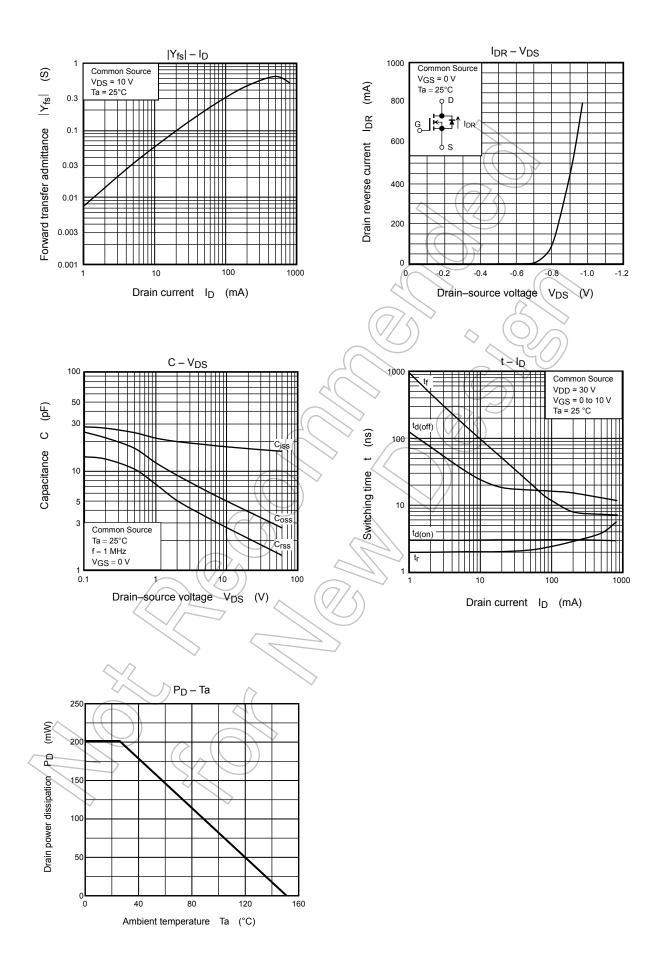
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.



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